Microelectronics, MEMS/NEMS

MI

2018-2022 Microsystems Technology Roadmap, June 2018 Canada's National Design Network

Technologies	2018	2019	2020	2021	2022	
Baseline CMOS technologies	Baseline CMOS technologies 350,180,130,65,28 nm will continue to be in the offering					
• CMOS flavors (HV, BCD, SOI)	✓ Additional Flavors: SiGe; Imaging (CIS), Low Power	CMOS integrated Non-Volatile Memory (ReRAM variations)	• 130nm SiGe with Opto			
Advanced CMOS		☆ 22nm SOI	☆ Photonics and uE co-design flow			
Compound Semiconductor	✓ CMOS Interposer			• GAA/Nanowires		
Heterogeneous Integration		☆ GaN (power switching)	☆ Advanced materials and processes for 2.5D Heterogenous Integration			
CAD Methodologies (Circuit/Device Modeling & Simulation)	✓ FinFET Simulation Modeling	Package PDK (Advanced CMOS)				
		(Advanced CMOS)	☆ non-VonNeumann			
		☆CMOS Wafer post-processing (integration/ packaging)	architecture modeling			
	☆ Josephson junction circuit	☆ Cryogenic CMOS	Graphene Coatings		Heat dissipation (minus fluidies)	
New and Emerging			Terahertz communication		(microfluidics)	
			(systems)		Cryogenic Memory	
• MEMS technologies (Application-	☆MEMS pressure	MEMS on LTCC	• RF MEMS		Low actuation	
specific)	sensors		(optical communications)		voltage devices	
Heterogeneous integration/ Packaging (MEMS, Photonics /		✓ Integrated CMOS / MEMS		Graphene-enabled		
Interposer)		CMUT on CMOS		MEMS		
	2018	2019	2020	2021	2022	

The Microsystems Technology Roadmap has 5 segments:

Microelectronics/MEMS/NEMS, Photonics, Embedded Systems, Packaging and Multi-scale Integration, and Nanofabrication Labs.

For more information, contact Gayathri Singh (singh@cmc.ca).

_	Key technology feature of a planned Product or Service; Development		
	activities are underway and/or supply chain is available.		
☆	CMC is seeking collaborators, suppliers to deliver capability.		
•	Anticipated technology feature based on roadmap sources.		